

## **BC182LB**

- NPN General Purpose Amplifier

  This device is designed for general purpose amplifier application at collector currents to 100mA.
- Sourced from process 10.



1. Emitter 2. Collector 3. Base

## Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	50	V
V <sub>CBO</sub>	Collector-Base Voltage	60	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
I <sub>C</sub>	Collector Current - Continuous	100	mA
T <sub>J,</sub> T <sub>STG</sub>	Storage Junction Temperature Range	- 55 ~ 150	°C

### **Electrical Characteristics** $T_C=25$ °C unless otherwise noted

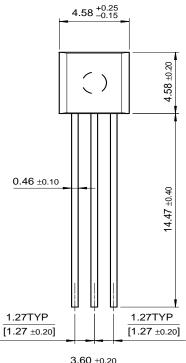
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Chara	cteristics					
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{C} = 2mA, I_{B} = 0$	50			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 10\mu A, I_E = 0$	60			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 100\mu A, I_C = 0$	6			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 50V, V_{BE} = 0$			15	nA
I <sub>EBO</sub>	Emitter-Base Leakage Current	$V_{EB} = 4V, I_{E} = 0$			15	nA
On Chara	cteristics					
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 5V, I_{C} = 10\mu A$ $V_{CE} = 5V, I_{C} = 100m A$	40 80			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 10 \text{mA}, I_B = 0.5 \text{mA}$ $I_C = 100 \text{mA}, I_B = 5 \text{mA}$			0.25 0.6	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = 100mA, I <sub>B</sub> = 5mA			1.2	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE} = 5V$ , $I_C = 2mA$	0.55		0.7	V
Dynamic (	Characteristics			•		•
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 5V, I_{C} = 10mA, f = 100MHz$	150			MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CE</sub> = 10V, I <sub>C</sub> = 0, f = 1MHz			5	pF
h <sub>fe</sub>	Small Signal Current Gain	V <sub>CE</sub> = 5V, I <sub>C</sub> = 2mA, f = 1KHz 240			500	
NF	Noise Figure	$V_{CE} = 5V$ , $I_{C} = 0.2mA$ $R_{S} = 2K\Omega$ , $f = 1KHz$ , $BW = 200Hz$			10	dB

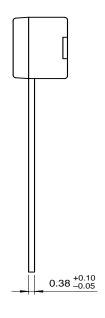
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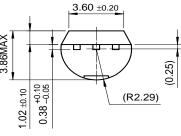
#### Thermal Characteristics $T_A=25^{\circ}\mathrm{C}$ unless otherwise noted Symbol Parameter Max. Units Total Device Dissipation @T<sub>A</sub>=25°C Derate above 25°C $P_{\mathsf{D}}$ 350 mW mW/°C 2.8 $R_{\theta JA}$ 357 mW/°C Thermal Resistance, Junction to Ambient $R_{\theta JC}$ °C/W Thermal Resistance, Junction to Case 125

# **Package Dimensions**

TO-92







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EnSigna™	$I^2C^{TM}$	OCXTM	RapidConfigure™	UHC™
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The Power Franchise™		OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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Rev. I1

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